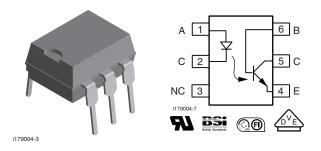


Vishay Semiconductors

Optocoupler, Phototransistor Output, Low Input Current, with Base Connection



DESCRIPTION

The MCT5211 is a optocoupler with a high efficiency AlGaAs LED optically coupled to a NPN phototransistor. The high performance LED makes operation at low input currents practical. The coupler is housed in a six pin DIP package. Isolation test voltage is $5300\ V_{RMS}$.

Because these parts have guaranteed CTRs at 1 mA and 3 mA, they are ideally suitable for interfacing from CMOS to TTL or LSTTL to TTL. They are also ideal for telecommunications applications such as ring or off-hook detection.

FEATURES

• Saturation CTR - MCT5211, > 100 % at $I_F = 1.6 \text{ mA}$



- High isolation voltage, 5300 V_{RMS}
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC



AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- BSI IEC 60950; IEC 60065
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending), available with option 1
- CSA 93751

ORDERING INFORMATION								
M C T 5 2 1 PART NUMBER	1 - X 0 # # T PACKAGE OPTION TAPE AND REEL Option 7 Option 9 > 0.7 mm							
ACENOV CERTIFIED (RACKACE	CTR (%)							
AGENCY CERTIFIED/PACKAGE	1 mA							
UL, BSI, CSA	> 110							
DIP-6	MCT5211							
SMD-6, option 7	MCT5211-X007T (1)							
SMD-6, option 9	MCT5211-X009T ⁽¹⁾							
UL, BSI, CSA, VDE	> 110							
SMD-6, option 7	MCT5211-X017T							

Note

- · Additional options may be possible, please contact sales office.
- (1) Also available in tubes, do not put T on the end.

VISHAY.

Vishay Semiconductors Optocoupler, Phototransistor Output, Low Input Current, with Base Connection

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Peak reverse voltage		V _R	6	V				
Forward continuos current		I _F	40	mA				
Power dissipation		P _{diss}	75	mW				
Derate linearly from 25 °C			1	mW/°C				
OUTPUT								
Collector emitter breakdown voltage		BV _{CEO}	30	V				
Emitter collector breakdown voltage		BV _{ECO}	7	V				
Collector base breakdown voltage		BV _{CBO}	70	V				
Power dissipation		P _{diss}	200	mW				
Derate linearly from 25 °C			2.6	mW/°C				
COUPLER								
Isolation test voltage		V _{ISO}	5300	V_{RMS}				
Total package dissipation (LED and detector)		P _{tot}	260	mW				
Derate linearly from 25 °C			3.5	mW/°C				
Creepage distance			≥ 7	mm				
Clearance distance			≥ 7	mm				
Comparative tracking index per DIN IEC 112/VDE 0303, part 1		СТІ	175					
loclation vaciations	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω				
Isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω				
Operating temperature		T _{amb}	- 55 to + 100	°C				
Storage temperature		T _{stg}	- 55 to + 150	°C				

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 5 \text{ mA}$		V_{F}		1.2	1.5	V
Reverse voltage	I _R = 10 μA		V_R	6			V
OUTPUT							
DC forward current gain	$V_{CE} = 5 \text{ V}, I_{C} = 100 \mu\text{A}$		h _{FE}	100	200		
Collector emitter breakdown voltage	I _C = 100 μA		BV _{CEO}	30			V
Emitter collector breakdown voltage	I _E = 100 μA		BV _{ECO}	7			V
Collector base breakdown voltage	I _E = 10 μA		BV _{CBO}	70			V
Collector emitter leakage voltage	V _{CE} = 10 V		I _{CEO}		5	100	nA
COUPLER							
Saturation voltage	$I_F = 1.6 \text{ mA}, I_C = 1.6 \text{ mA}$	MCT5211	V _{CEsat}		0.25	0.4	V

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.



Optocoupler, Phototransistor Output, Low Vishay Semiconductors Input Current, with Base Connection

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio (collector emitter saturated)	$V_{CE} = 0.4 \text{ V}, I_F = 1.6 \text{ mA}$	MCT5211	CTR _{CEsat}	100	200		%
	V _{CE} = 0.4 V, I _F = 1 mA	MCT5211	CTR _{CEsat}	75	150		%
Current transfer ratio	$V_{CE} = 5 \text{ V}, I_F = 1.6 \text{ mA}$	MCT5211	CTR	150	300		%
	V _{CE} = 5 V, I _F = 1 mA	MCT5211	CTR	110	225		%
Current transfer ratio (collector base)	$V_{CE} = 4.3 \text{ V}, I_F = 1.6 \text{ mA}$	MCT5211	CTR _{CB}	0.3	0.6		%
	$V_{CE} = 4.3 \text{ V}, I_F = 1 \text{ mA}$	MCT5211	CTR _{CB}	0.25	0.5		%

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Propagation delay high to low	$R_L = 750~\Omega$, $I_F = 1.6~mA$, $V_{CC} = 5~V$	MCT5211	t _{PHL}		20		μs
	$R_L = 1.5 \text{ k}\Omega$, $I_F = 1 \text{ mA}$, $V_{CC} = 5 \text{ V}$	MCT5211	t _{PHL}		40		μs
Propagation delay low to high	R_L = 750 Ω , I_F = 1.6 mA, V_{CC} = 5 V	MCT5211	t _{PLH}		20		μs
	$R_L = 1.5 \text{ k}\Omega$, $I_F = 1 \text{ mA}$, $V_{CC} = 5 \text{ V}$	MCT5211	t _{PLH}		40		μs

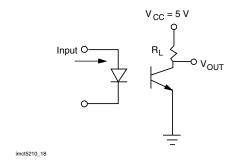


Fig. 1 - Switching Schematic

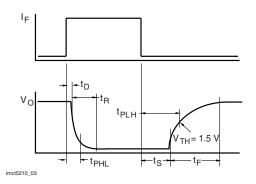


Fig. 2 - Switching Waveform

Vishay Semiconductors Optocoupler, Phototransistor Output, Low Input Current, with Base Connection



TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

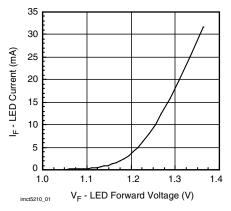


Fig. 3 - Forward Current vs. Forward Voltage

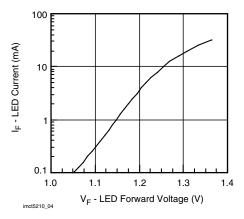


Fig. 4 - LED Forward Current vs. Forward Voltage

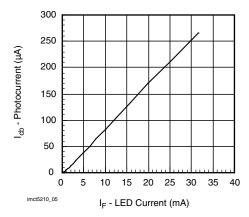


Fig. 5 - Collector Base Photocurrent vs. LED Current

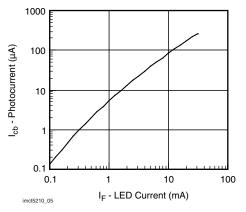


Fig. 6 - Photocurrent vs. LED Current

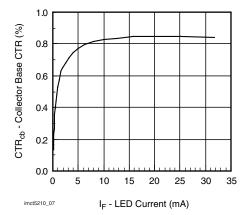


Fig. 7 - Collector Base CTR vs. LED Current

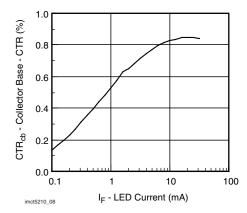


Fig. 8 - Collector Base CTR vs. LED Current



Optocoupler, Phototransistor Output, Low Vishay Semiconductors Input Current, with Base Connection

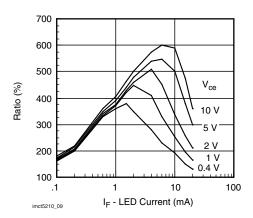


Fig. 9 - CTR vs. LED Current

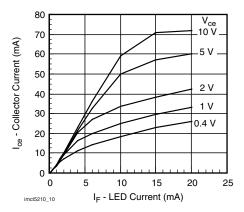


Fig. 10 - Collector Current vs. LED Current

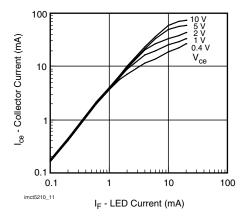


Fig. 11 - Collector Current vs. LED Current

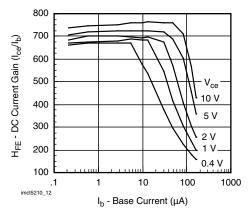


Fig. 12 - Transistor Current Gain vs. Base Current

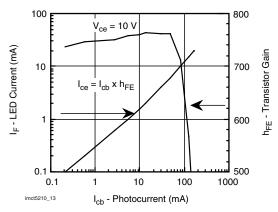


Fig. 13 - Transfer Curve

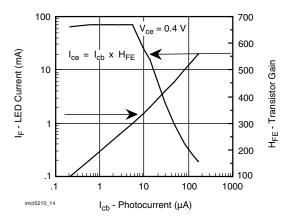


Fig. 14 - Transfer Curve

Vishay Semiconductors Optocoupler, Phototransistor Output, Low Input Current, with Base Connection



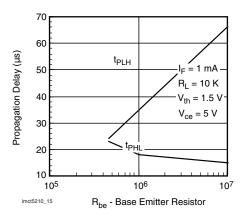


Fig. 15 - Propagation Delay vs. Base Emitter Resistor

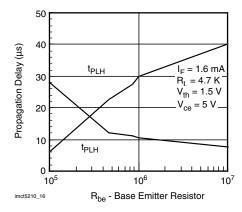


Fig. 16 - Propagation Delay vs. Base Emitter Resistor

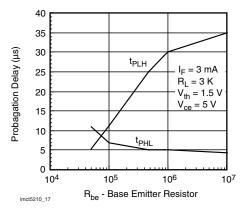
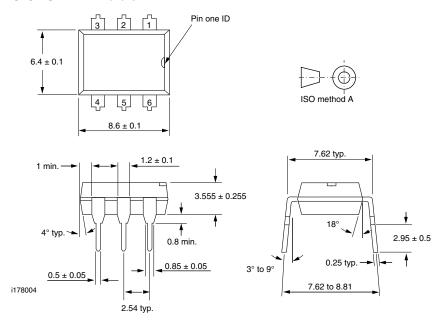


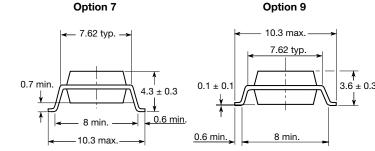
Fig. 17 - Propagation Delay vs. Base Emitter Resistor

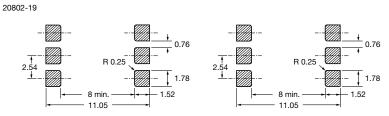


Optocoupler, Phototransistor Output, Low Vishay Semiconductors Input Current, with Base Connection

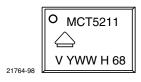
PACKAGE DIMENSIONS in millimeters







PACKAGE MARKING (example)



Notes

- Only option 7 is reflected in the package marking.
- The VDE logo is only marked on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking.

Legal Disclaimer Notice



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Document Number: 91000 www.vishay.com
Revision: 11-Mar-11 1